

Rectifier Diode Module Types MDO1201-16N1 to MDO1201-22N1

Absolute Maximum Ratings

V_{RRM} [V]	Type
1600	MDO1201-16N1
1800	MDO1201-18N1
2000	MDO1201-20N1
2200	MDO1201-22N1

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage ¹⁾	1600-2200	V
V_{RSM}	Non-repetitive peak reverse voltage ¹⁾	1700-2300	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, $T_c=55^\circ\text{C}$ ²⁾	1950	A
$I_{F(AV)M}$	Maximum average forward current, $T_c=100^\circ\text{C}$ ²⁾	1280	
$I_{F(AV)M}$	Maximum average forward current, $T_c=85^\circ\text{C}$ ²⁾	1520	
$I_{F(RMS)M}$	Nominal RMS forward current, $T_c=25^\circ\text{C}$ ²⁾	3665	
$I_{T(d.c.)}$	D.C. forward current, $T_c=25^\circ\text{C}$	2940	
I_{FSM}	Peak non-repetitive surge $t_p=10\text{ms}$, $V_{rm}=60\%V_{RRM}$ ³⁾	36	kA
I_{FSM2}	Peak non-repetitive surge $t_p=10\text{ms}$, $V_{rm}\leq 10\text{V}$ ³⁾	40	kA
I^2t	I^2t capacity for fusing $t_p=10\text{ms}$, $V_{rm}=60\%V_{RRM}$ ³⁾	6.48×10^6	A^2s
I^2t	I^2t capacity for fusing $t_p=10\text{ms}$, $V_{rm}\leq 10\text{V}$ ³⁾	8.00×10^6	A^2s
V_{ISOL}	Isolation Voltage ⁴⁾	3000	V
$T_{vj\text{ op}}$	Operating temperature range	-40 to +160	$^\circ\text{C}$
T_{stg}	Storage temperature range	-55 to +160	$^\circ\text{C}$

Notes:

- 1) De-rating factor of 0.13% per $^\circ\text{C}$ is applicable for T_{vj} below 25°C .
- 2) Single phase; 50 Hz, 180° half-sinewave.
- 3) Half-sinewave, 160°C T_{vj} initial.
- 4) AC RMS voltage, 50 Hz, 1min test

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS ¹⁾	UNITS
V _{FM}	Maximum peak forward voltage	-	-	0.97	I _{FM} =1700A	V
		-	-	1.15	I _{FM} =3400A	V
V _{T0}	Threshold voltage	-	-	0.80		V
r _T	Slope resistance	-	-	0.10		mΩ
I _{R_{RRM}}	Peak reverse current	-	-	5	Rated V _{RRM} , T _j =25°C	mA
		-	-	70	Rated V _{RRM}	
R _{thJC}	Thermal resistance, junction to case	-	-	0.042		K/W
R _{thCH}	Thermal resistance, case to heatsink	-	-	0.010		K/W
F ₁	Mounting torque (to heatsink)	5.1	-	6.9		Nm
F ₂	Mounting torque (to terminals)	16.2	-	19.8		Nm
W _t	Weight	-	2.8	-		kg

Notes:

1) Unless otherwise indicated T_{vj}=160°C.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
16	1600	1700	900
18	1800	1900	1000
20	2000	2100	1100
22	2200	2300	1200

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_{vj} below 25°C.

4.0 Repetitive dv/dt

Standard dv/dt is 1000V/μs.

5.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

6.0 Computer Modelling Parameters

6.1 Diode dissipation calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\max} - T_C$$

Where $V_{T0} = 0.80V$, $r_T = 0.10m\Omega$.

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	0.0460	0.0448	0.0439	0.0420
Sine wave	0.0453	0.0442	0.0428	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

6.2 Calculating diode V_F using ABCD coefficients – For loss calculations

The forward characteristic, I_F vs. V_F , is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the equation for V_F in terms of I_T given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The ABCD constants are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		160°C Coefficients	
A	0.7455207	A	0.4701738
B	0.04542294	B	0.05180998
C	7.02344×10^{-5}	C	8.913584×10^{-5}
D	-1.458635×10^{-3}	D	-8.375765×10^{-4}

6.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{-\frac{t}{\tau_p}} \right)$$

n = number of terms in the series and
 t = duration of heating pulse in seconds.
 r_t = thermal resistance at time t .

r_p = Amplitude of p_{th} term.
 τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Junction to Case			
Term	1	2	3
r_p	0.01904887	0.01751398	5.364393×10^{-3}
τ_p	21.99824	1.079638	0.0132514

Curves

Figure 1 – Forward Characteristics of Limit Device

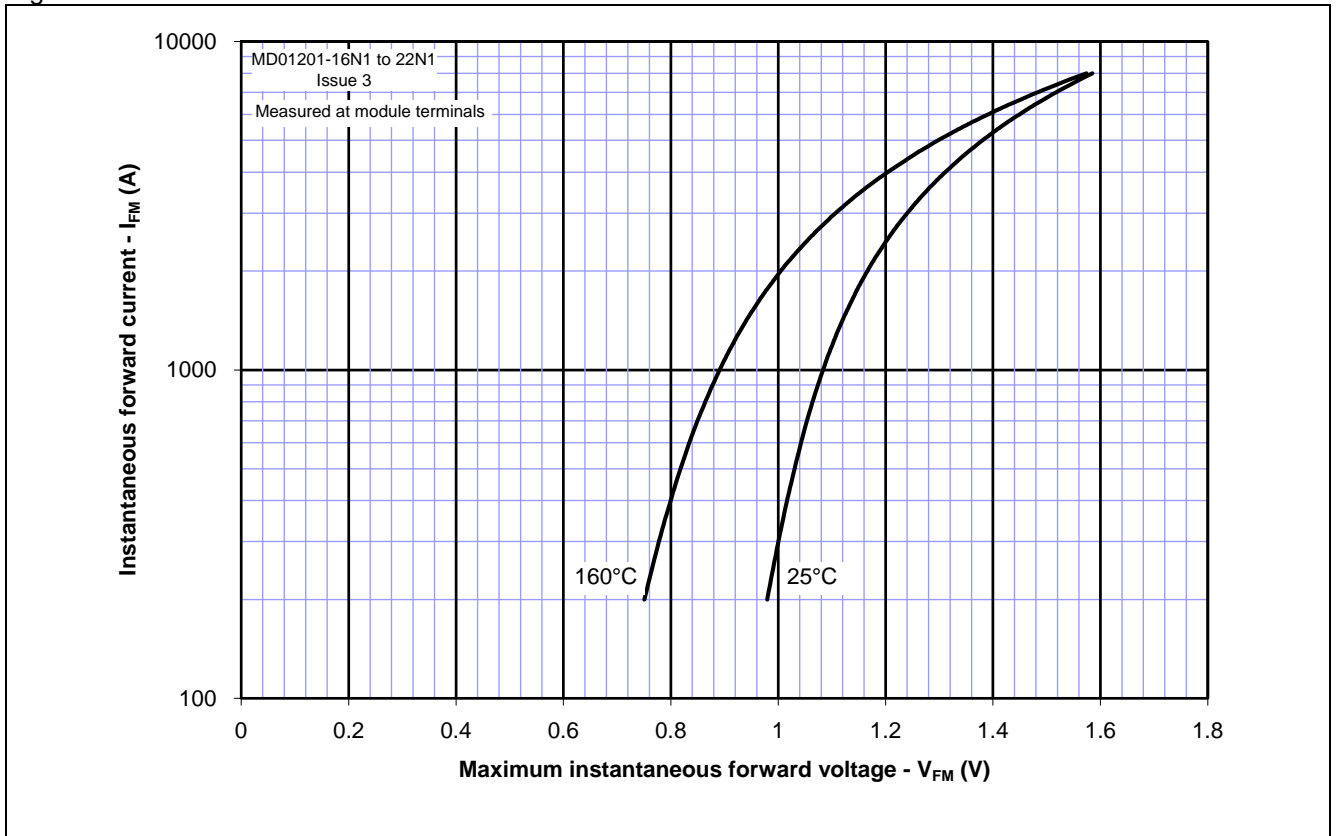


Figure 2 – Transient Thermal Impedance

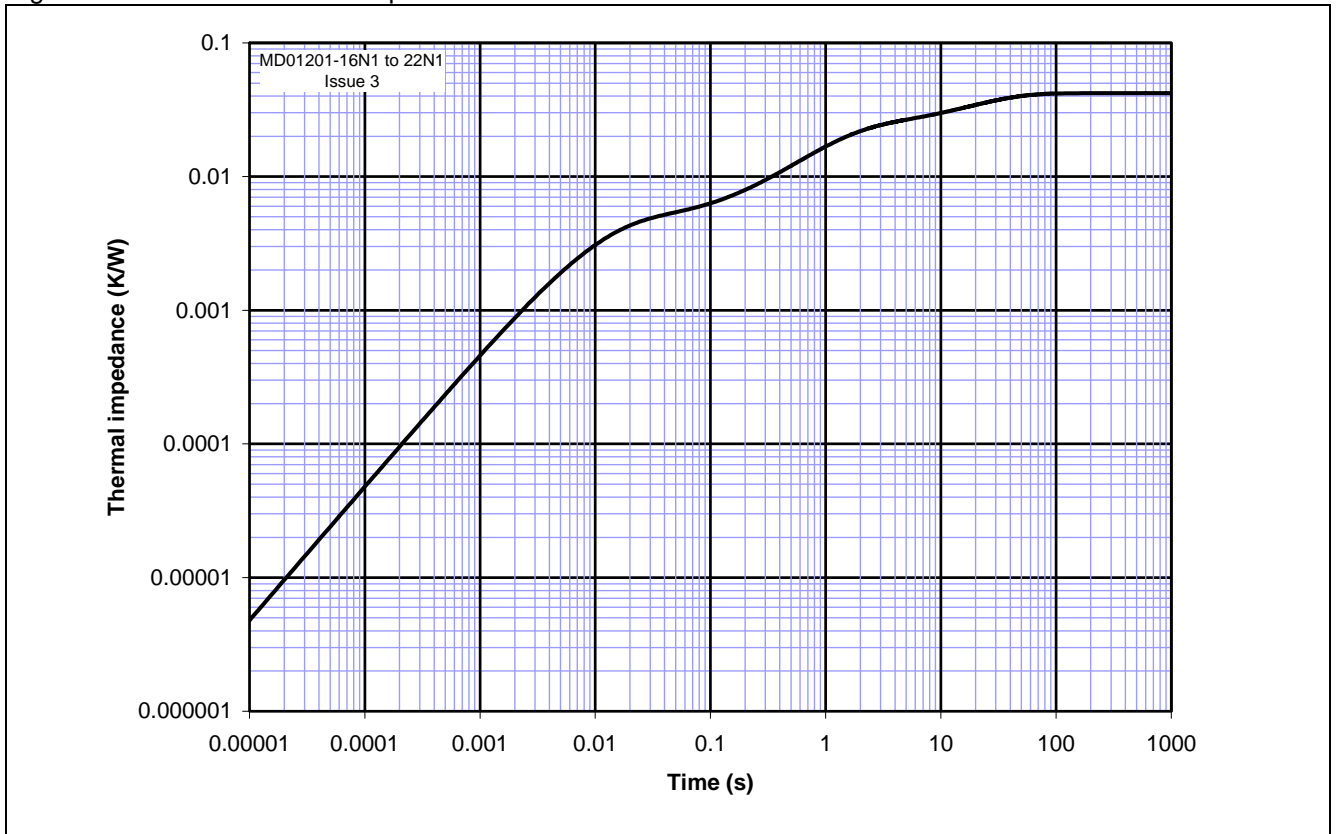


Figure 3 – Forward current vs. Power dissipation

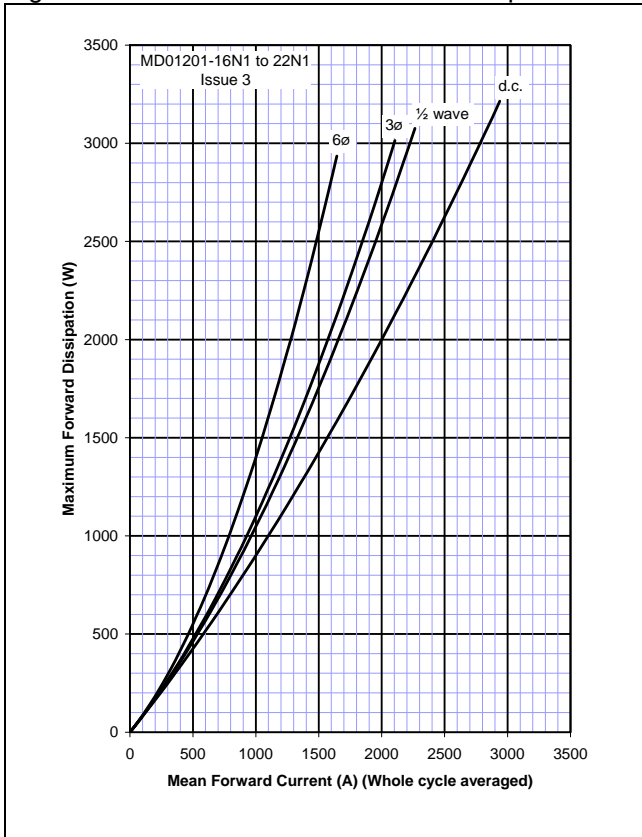


Figure 4 – Forward current vs. Heatsink temperature

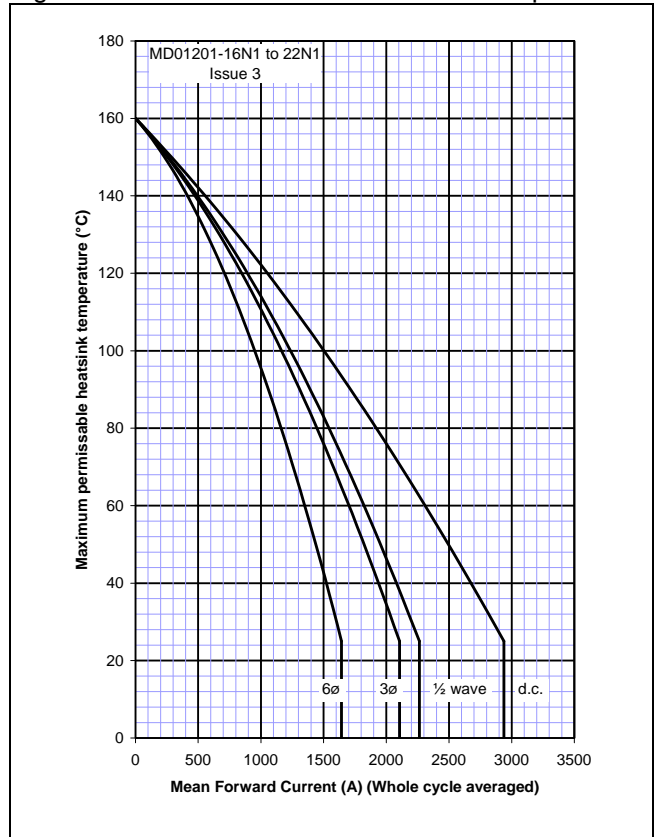
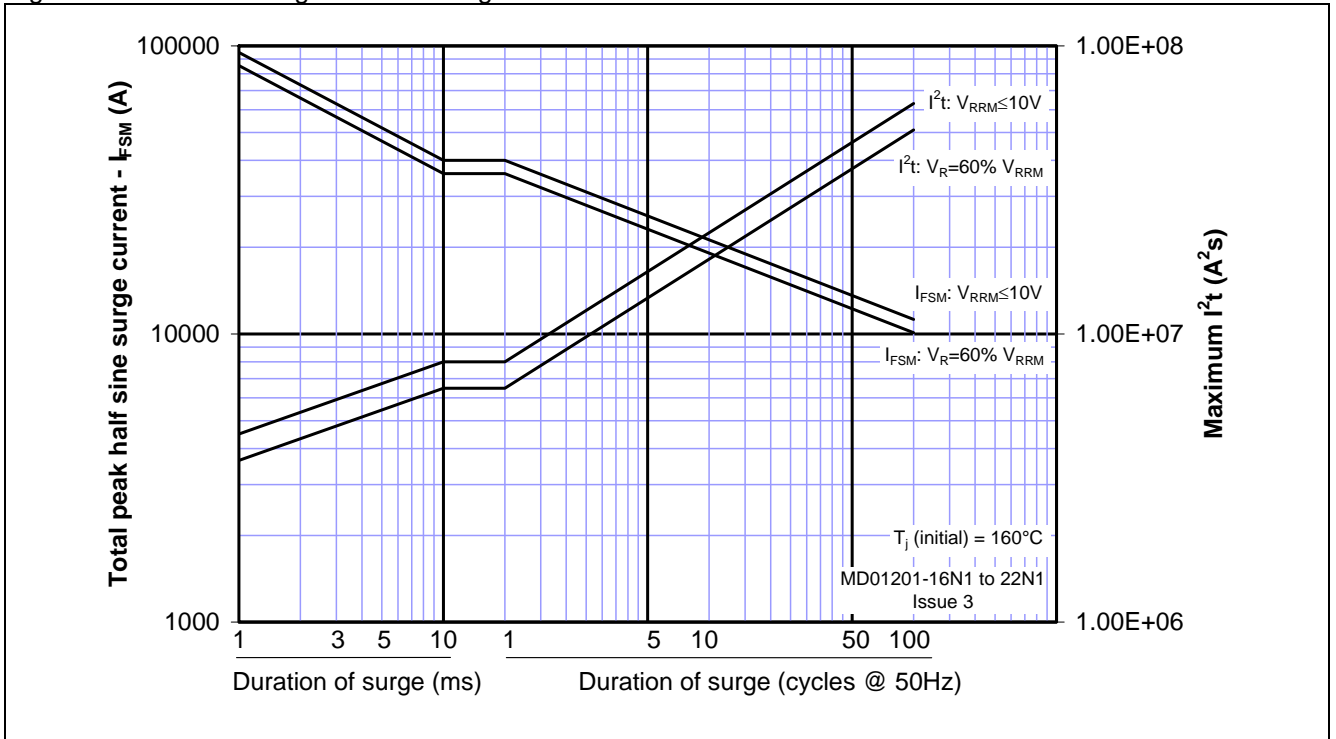
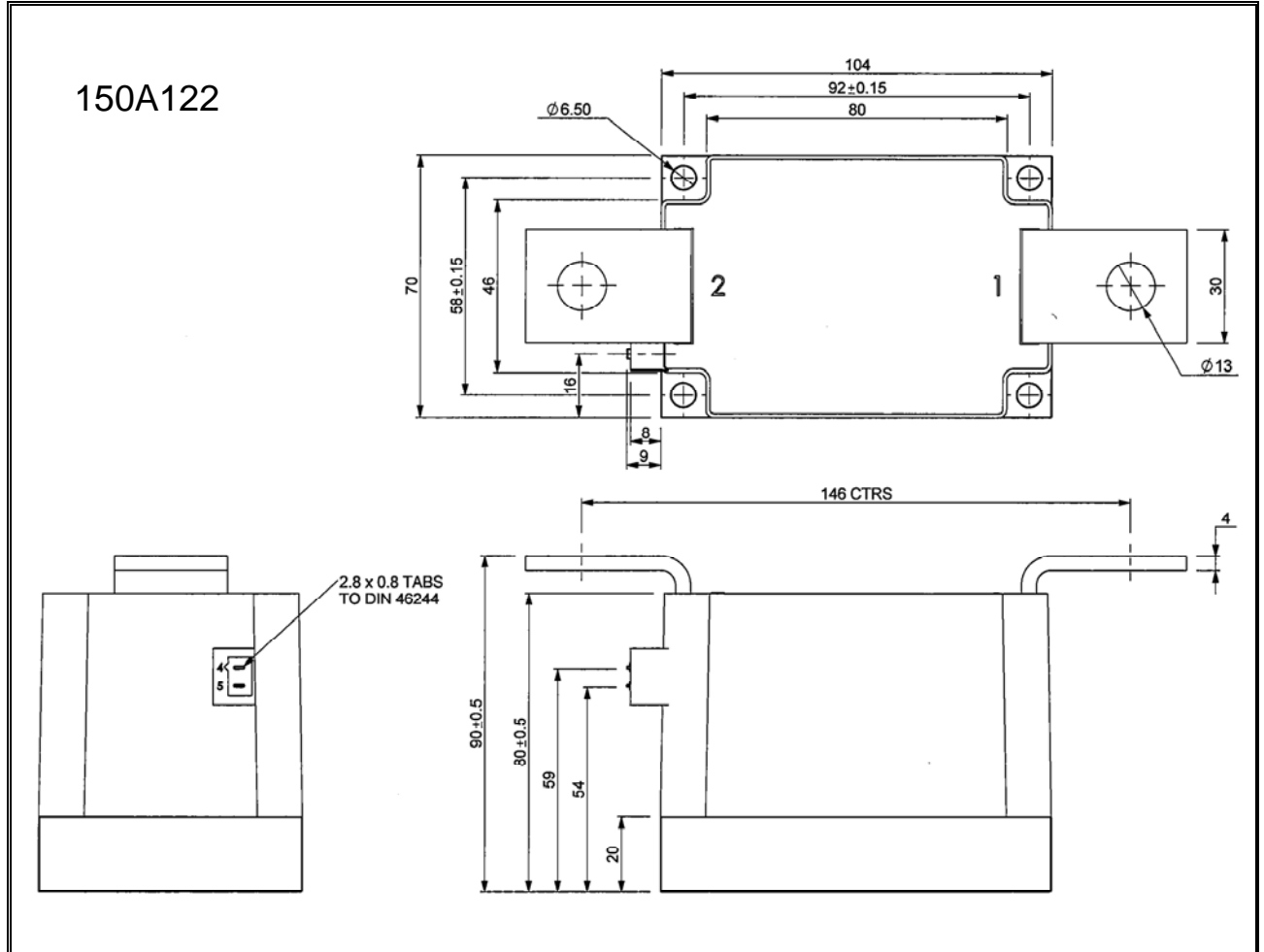


Figure 5 – Maximum surge and I²t Ratings



Outline Drawing & Ordering Information



ORDERING INFORMATION					
(Please quote 11 digit code as below)					
M	DO	1201	◆◆	N	1
Fixed Type Code	Fixed Configuration code	Nominal Current Rating	Voltage code $V_{RRM}/100$ 16-22	Standard diode	Fixed Version Code

Typical order code: MDO1201-22N1, 2200V V_{RRM} Rectifier Diode Module

IXYS Semiconductor GmbH
 Edisonstraße 15
 D-68623 Lampertheim
 Tel: +49 6206 503-0
 Fax: +49 6206 503-627
 E-mail: marcom@ixys.de



www.ixys.com

IXYS Corporation
 1590 Buckeye Drive
 Milpitas CA 95035 7418 USA
 Tel: +1 (408) 547 9000
 Fax: +1 (408) 496 0670
 E-mail: sales@ixys.net

WESTCODE

An IXYS Company

www.westcode.com

Westcode Semiconductors Ltd
 Langley Park Way, Langley Park,
 Chippenham, Wiltshire, SN15 1GE.
 Tel: +44 (0)1249 444524
 Fax: +44 (0)1249 659448
 E-mail: WSL.sales@westcode.com

IXYS Long Beach, Inc
 2500 Mira Mar Ave, Long Beach
 CA 90815
 Tel: +1 (562) 296 6584
 Fax: +1 (562) 296 6585
 E-mail: service@ixyslongbeach.com

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